

# N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A) <sup>a</sup>	Q <sub>g</sub> (Typ.)		
20	0.033 at V <sub>GS</sub> = 4.5 V	6.8	10 nC		
	0.045 at V <sub>GS</sub> = 2.5 V	6.8	10110		

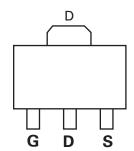
#### **FEATURES**

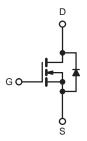
· DT-Trench Power MOSFET



#### **APPLICATIONS**

· Load Switches for Portable Devices





N-Channel MOSFET

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20	V	
Gate-Source Voltage		V <sub>GS</sub>	± 12		
	T <sub>C</sub> = 25 °C		6.8 <sup>a</sup>		
Continuous Drain Current (T <sub>.1</sub> = 150 °C)	T <sub>C</sub> = 70 °C		6 <sup>a</sup>		
Continuous Brain Current (1) = 130 °C)	T <sub>A</sub> = 25 °C	l <sub>D</sub>	6.8 <sup>a, b, c</sup>		
	T <sub>A</sub> = 70 °C		6 <sup>a, b, c</sup>	A	
Pulsed Drain Current		I <sub>DM</sub>	30		
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C	I <sub>S</sub>	5.2		
Continuous Source-Diain Diode Current	T <sub>A</sub> = 25 °C	l 's	2.1 <sup>b, c</sup>		
	T <sub>C</sub> = 25 °C		6.3		
Maximum Pawar Dissipation	T <sub>C</sub> = 70 °C	P <sub>D</sub>	4	W	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	1 'D	2.5 <sup>b, c</sup>	VV	
	T <sub>A</sub> = 70 °C		1.6 <sup>b, c</sup>		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	
Soldering Recommendations (Peak Tempera		260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>a, c, d</sup>	t ≤ 5 s	R <sub>thJA</sub>	40	50	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	$R_{thJF}$	15	20	] 0, **	

- a. Package limited, T<sub>C</sub> = 25 °C.
  b. Surface Mounted on 1" x 1" FR4 board.
- c. t = 10 s.
- d. Maximum under Steady State conditions is 95 °C/W.
- e. See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	<u>.</u>				I.	•
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20			V
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	1 - 250		25		mV/°C
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_{J}$	$I_D = 250  \mu A$		- 4.0		
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.6		1.5	V
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA
	I <sub>DSS</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$			1	
Zero Gate Voltage Drain Current		V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			10	μA
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α
	` '	$V_{GS} = 4.5 \text{ V}, I_D = 8.3 \text{ A}$		0.026	0.033	Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 4.5 \text{ A}$		0.030	0.045	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_D = 8.3 \text{ A}$		45		S
Dynamic <sup>b</sup>						1
Input Capacitance	C <sub>iss</sub>			1200		pF
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		220		
Reverse Transfer Capacitance	C <sub>rss</sub>			100		
Total Cata Chausa	Qg	$V_{DS} = 10 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 8.3 \text{ A}$		22	33	nC
Total Gate Charge				10	15	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 8.3 \text{ A}$		2.5		
Gate-Drain Charge	$Q_{gd}$			1.7		
Gate Resistance	$R_g$	f = 1 MHz		2.4		Ω
Turn-on Delay Time	t <sub>d(on)</sub>			15	25	
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 1.5 $\Omega$		10	15	ns
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong 6.7$ A, $V_{GEN}=4.5$ V, $R_g=1$ $\Omega$		35	55	
Fall Time	t <sub>f</sub>			12	20	
Turn-on Delay Time	t <sub>d(on)</sub>			10	15	
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 1.5 $\Omega$		12	20	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong 6.7$ A, $V_{GEN}$ = 10 V, $R_g$ = 1 $\Omega$		25	40	
Fall Time	t <sub>f</sub>			10	15	
<b>Drain-Source Body Diode Characteristic</b>	s			•		•
Continuous Source-Drain Diode Current	I <sub>S</sub>	$T_C = 25  ^{\circ}C$			5.2	А
Pulse Diode Forward Current	I <sub>SM</sub>				30 A	
Body Diode Voltage	$V_{SD}$	$I_S = 6.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V
Body Diode Reverse Recovery Time	t <sub>rr</sub>			20	40	ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	L = 6.7 A dl/dt = 100 A/vo T = 25.00		10	20	nC
Reverse Recovery Fall Time	t <sub>a</sub>	$I_F = 6.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		10		ns
Reverse Recovery Rise Time	t <sub>b</sub>			10		

#### Notes:

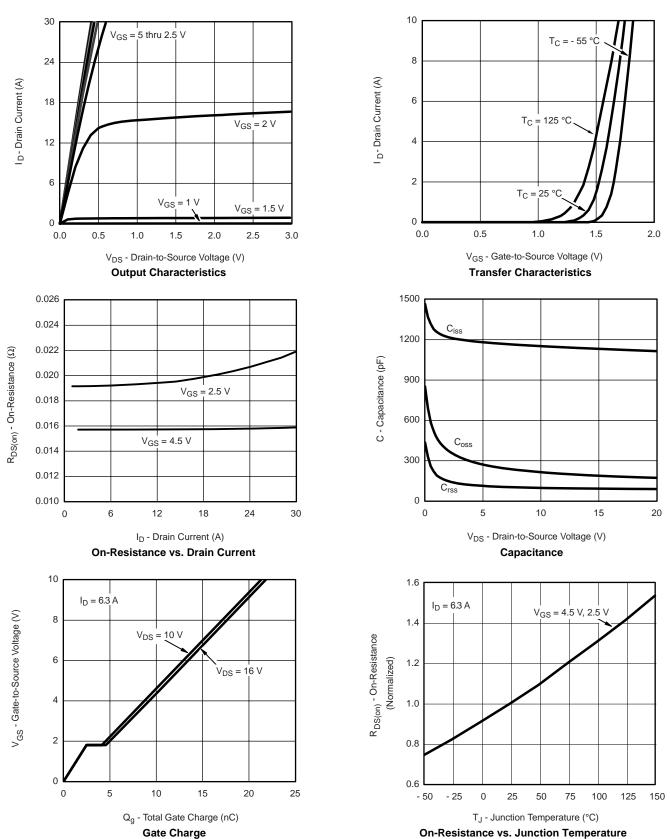
- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





0.050

0.040

0.030

0.020

0.010

0.000

0

R<sub>DS(on)</sub> - On-Resistance (Ω)



#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

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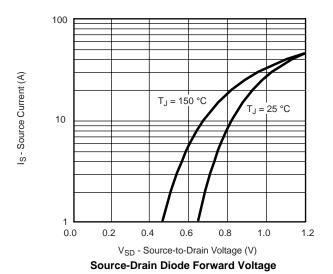
 $I_{D} = 6.3 \text{ A}$ 

 $T_J = 125 \, ^{\circ}C$ 

 $T_J = 25 \, ^{\circ}C$ 

4

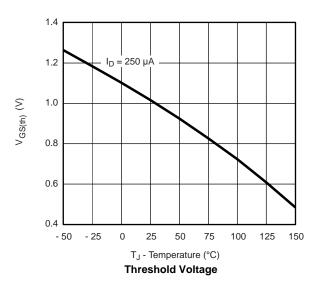
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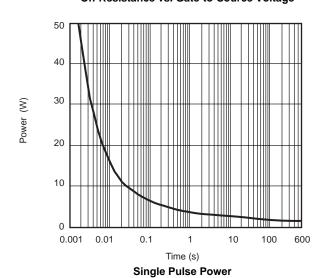


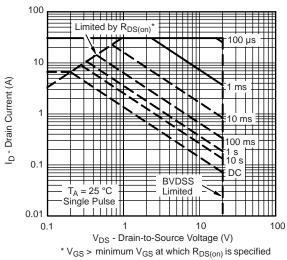


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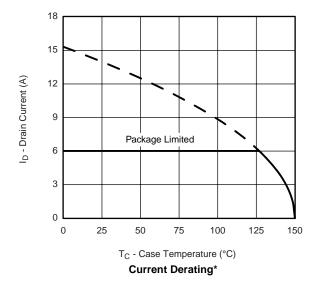


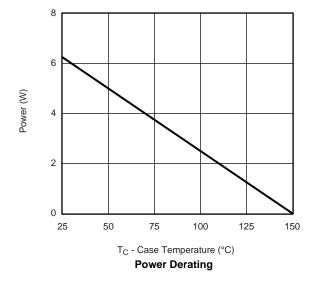


Safe Operating Area, Junction-to-Ambient



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

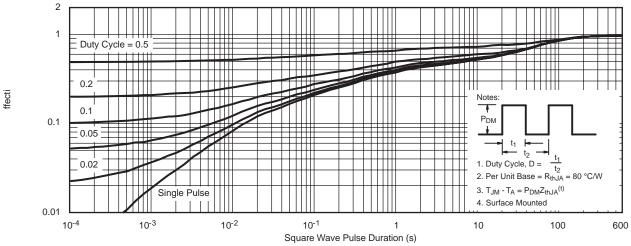




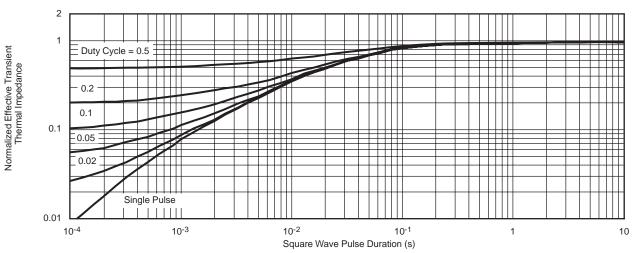
<sup>\*</sup> The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot





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